

#### **60V NPN SMALL SIGNAL TRANSISTOR IN SOT323**

#### **Features**

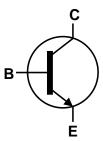
- BV<sub>CEO</sub> > 40V
- I<sub>C</sub> = 200mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMST3906
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

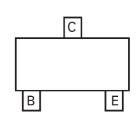
- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)







Device Symbol



Pin-out Top View

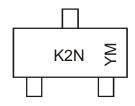
### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMST3904-7-F	AEC-Q101	K2N	7	8	3,000
MMST3904Q-7-F	Automotive	K2N	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



$$\begin{split} &K2N = Product\ Type\ Marking\ Code \\ &YM = Date\ Code\ Marking \\ &Y\ or\ \overline{Y} = Year\ (ex:\ D=2016) \\ &M\ or\ \overline{M} = Month\ (ex:\ 9=September) \end{split}$$

Date Code Kev

Year	2016	2	017	2018	2019	2020	2021	2022	2 20	23 2	2024	2025	2026
Code	D		E	F	G	Н	I	J	ŀ	(	L	M	N
Month	ı	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	)	1	2	3	4	5	6	7	8	9	0	N	D

July 2016



## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	Ic	200	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# ESD Ratings (Note 7)

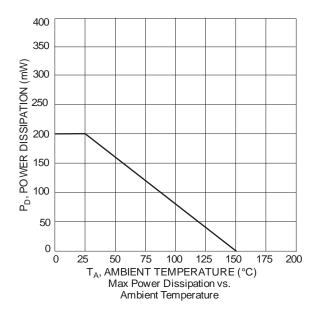
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

<sup>7.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





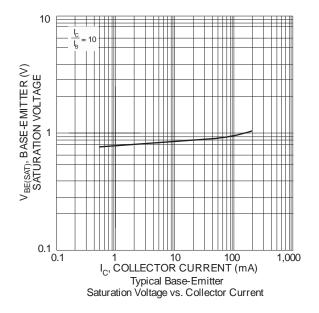
# **Electrical Characteristics** ( $@T_A = +25$ °C, unless otherwise specified.)

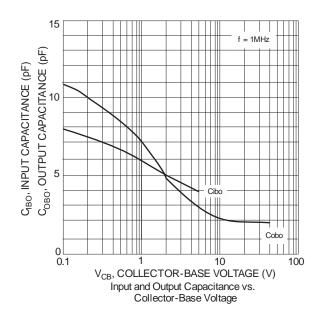
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60		V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	40		V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	_	V	$I_E = 10\mu A, I_C = 0$
Collector Cutoff Current	I <sub>CEX</sub>	_	50	nA	$V_{CE} = 30V$ , $V_{EB(OFF)} = 3V$
Base Cutoff Current	I <sub>BL</sub>	_	50	nA	$V_{CE} = 30V$ , $V_{EB(OFF)} = 3V$
ON CHARACTERISTICS (Note 8)					
		40			$I_C = 100 \mu A$ , $V_{CE} = 1 V$
		70	_		$I_C = 1mA$ , $V_{CE} = 1V$
DC Current Gain	h <sub>FE</sub>	100	300	_	$I_C = 10mA$ , $V_{CE} = 1V$
		60	_		$I_C = 50$ mA, $V_{CE} = 1$ V
		30	—		$I_C = 100 \text{mA}, V_{CE} = 1 \text{V}$
Collector-Emitter Saturation Voltage	V		0.25	V	$I_C = 10mA$ , $I_B = 1mA$
Collector-Emilier Saturation voltage	V <sub>CE(SAT)</sub>		0.30	V	$I_C = 50 \text{mA}, I_B = 5 \text{mA}$
Base-Emitter Saturation Voltage	V	0.65	0.85	V	$I_C = 10mA$ , $I_B = 1mA$
ŭ	V <sub>BE</sub> (SAT)	—	0.95	V	$I_C = 50 \text{mA}, I_B = 5 \text{mA}$
SMALL SIGNAL CHARACTERISTICS		•	,		
Output Capacitance	$C_{ m obo}$	_	4	pF	$V_{CB} = 5V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>ibo</sub>	_	8	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_{C} = 0$
Input Impedance	h <sub>ie</sub>	1	10	kΩ	
Voltage Feedback Ratio	h <sub>re</sub>	0.5	8.0	x 10 <sup>-4</sup>	$V_{CE} = 10V, I_{C} = 1mA,$
Small Signal Current Gain	h <sub>fe</sub>	100	400	_	f = 1.0MHz
Output Admittance	h <sub>oe</sub>	1	40	μS	
Current Gain-Bandwidth Product	f <sub>T</sub>	300	_	MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz
Noise Figure	NF		5	dB	$V_{CC} = 5V, I_C = 100\mu A,$ $R_S = 1k\Omega, f = 1MHz$
SWITCHING CHARACTERISTICS	•	•	•	•	
Delay Time	t <sub>D</sub>	_	35	ns	$V_{CC} = 3V$ , $I_C = 10mA$ ,
Rise Time	t <sub>R</sub>		35	ns	$V_{BE(OFF)} = -0.5V$ , $I_{B1} = 1mA$

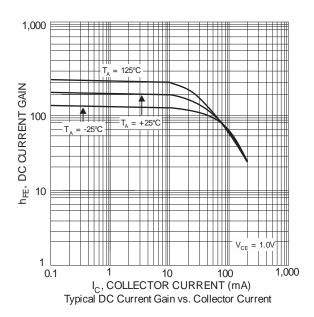
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

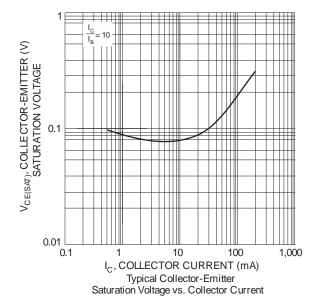


## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







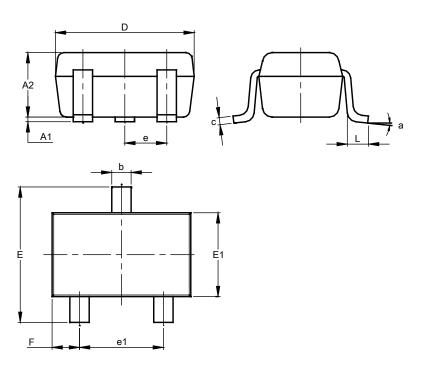




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT323**

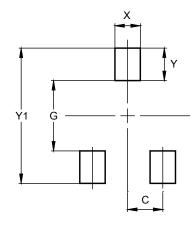


SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
С	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C	).650 B	SC			
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°	-			
All Dimensions in mm						

# **Suggested Pad Layout**

 $\label{prop:lease} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

#### SOT323



Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500



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